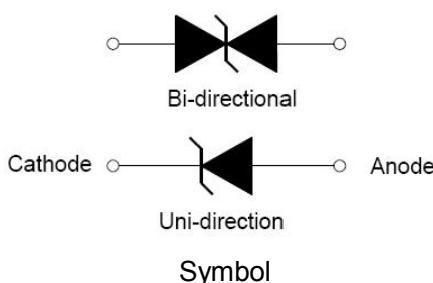


SMB

Features

- Peak power dissipation 3000W@10 x 1000 us Pulse
- Low incremental surge resistance
- Excellent clamping capability
- Glass passivated junction
- Fast response time
- Typical IR less than 1uA
- Halogen free and RoHS compliant

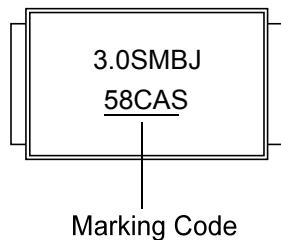
Mechanical Data

CASE: SMBJ(DO-214AA) Molded Plastic

Polarity: By cathode band denotes uni-directional device,

none cathode band denotes bi-directional device

Mounting Position: Any

Making Code & information


Package	Packing Description	Packing Quantity
SMB	Tape/Reel,13" reel	3000

3.0SMDJ - 58 - C A S

CSR Tech
5% V_{BR} Voltage Tolerance
Bidirectional
 V_{RWM} Voltage
Series Code

Maximum Ratings & Thermal Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Units
Peak Pulse Power Dissipation on 10/1000 us Waveform (Note 1, 2, FIG.1)	P_{PPM}	Min 3000	W
Power Dissipation on Infinite Heat Sink at $T_L=50^\circ\text{C}$	P_D	6.5	W
Peak Pulse Voltage on 10/700 us Waveform (Note 1, FIG.3)	V_{PPM}	4000	V
Peak Pulse Current on 10/1000us Waveform (Note 1, FIG.3)	I_{PPM}	32.1	A
Peak Forward Surge Current, 8.3ms Single Half Sine-Wave (Note 2.3)	I_{FSM}	300	A
Operating Junction Temperature Range	T_J	-55 to 150	°C
Storage Temperature Range	T_{STG}	-55 to 150	°C

Notes:

1. Non-repetitive current pulse, per Fig.3 and derated above $T_A=25^\circ\text{C}$ per Fig.2.
2. Mounted on 5.0x5.0mm² (0.03mm thick) Copper Pads to each terminal.
3. Measured on 8.3ms single half sine-wave, or equivalent square wave, for Unidirectional device only.

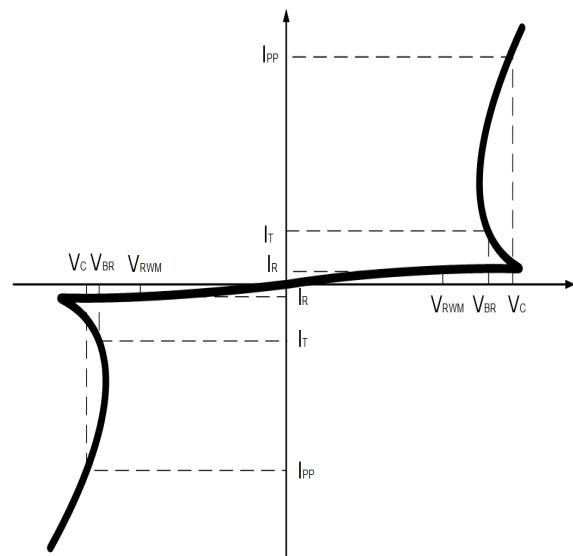
Electrical Characteristics

(Ratings at 25°C ambient temperature unless otherwise specified).

Type Number	Marking	Reverse Stand-Off Voltage	Breakdown Voltage Min. @ I_T	Breakdown Voltage Max. @ I_T	Test Current	Maximum Clamping Voltage @ I_{PP}			Peak Pulse Current	Reverse Leakage @ V_{RMW}
3.0SMBJ58CAS	3.0SMBJ 58CAS	$V_{RMW}(V)$	$V_{BR\ MIN}(V)$	$V_{BR\ MAX}(V)$	$I_T\ (mA)$	$V_c(V)$			$I_{PP}(A)$	$I_R(uA)$
		58	64.4	71.2	1.0	48(min)	60(typ)	93(max)	32.1	2

I - V Curve Characteristics

Parameter	Definition
C_J	Junction Capacitance - typical capacitance measured with 0V or V_R bias
I_{PP}	Peak Pulse Current - maximum rated peak impulse current
V_c	Clamping Voltage - Peak voltage measured across the suppressor at a specified I_{ppm} (peak impulse current)
V_{BR}	Breakdown Voltage - Maximum voltage that flows through the TVS at a specified test current (I_T)
I_R	Leakage Current - maximum peak off-state current measured at V_R
V_R	Peak Off-state Voltage - maximum voltage that can be applied while maintaining off state



Ratings and Characteristic Curves

(Ratings at 25°C ambient temperature unless otherwise specified).

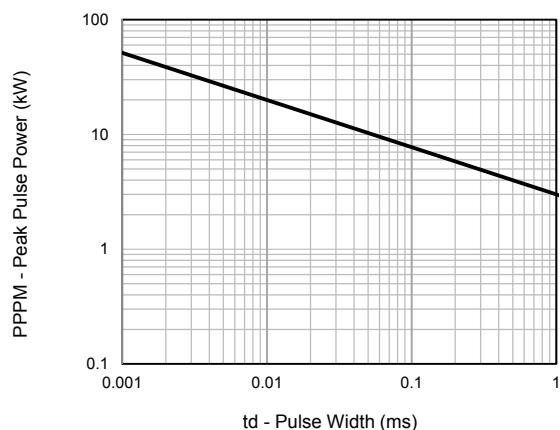


Fig.1 - Peak Pulse Power Rating

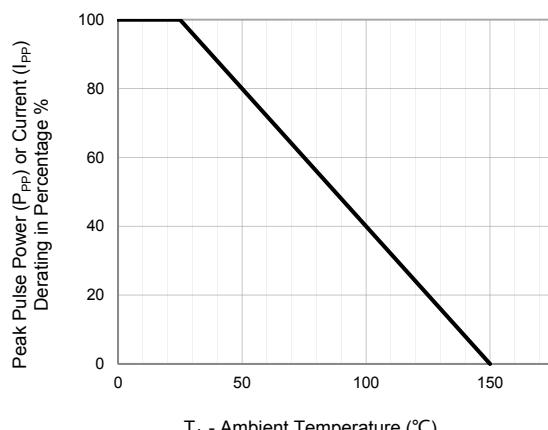


Fig.2 - Pulse Derating Curve

Ratings and Characteristic Curves

(Ratings at 25°C ambient temperature unless otherwise specified).

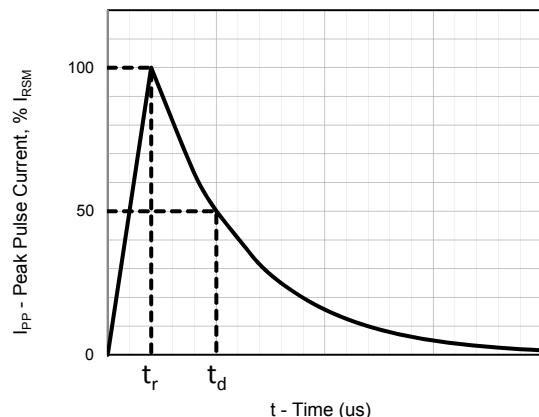


Fig.3 - Pulse Waveform

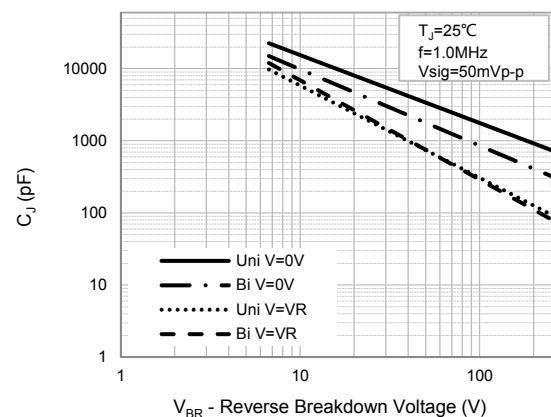


Fig.4 - Typical Junction Capacitance

Package Outline Dimensions: SMB(DO-214AA)

Dim	Millimeters		Inches	
	Min	Max	Min	Max
L	4.4	4.6	0.173	0.181
D	3.5	3.7	0.138	0.146
D1	1.9	2.1	0.075	0.083
T	5.1	5.48	0.201	0.216
T1	1.0	1.6	0.039	0.063
d	-	0.2	-	0.008
H	2.2	2.45	0.087	0.096
H1	2.15	2.35	0.085	0.093